



1.0A SURFACE MOUNT GLASS PASSIVATED BRIDGE RECTIFIER

Features

- Glass Passivated Die Construction
- Low Forward Voltage Drop, High Current Capability
- Surge Overload Rating to 50A Peak
- Designed for Surface Mount Application
- UL Listed Under Recognized Component Index, File Number E94661
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

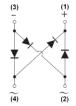
- Case: DF-S
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Tin. Solderable per MIL-STD-202, Method 208 @3
- Polarity: As Marked on Case
- Weight: 0.38 grams (Approximate)



Top View



Pin Diagram



Internal Schematic

Ordering Information (Note 4)

Part Number	Case	Packaging
DFxS	DF-S	50/Tube
DFxS-T	DF-S	1500/Tape & Reel, 13-inch

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- ${\it 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.}\\$

Marking Information



OH = Manufacturers' Code Marking

DFxxxS = Product Type Marking Code,ex:DF10S

YWW = Date Code Marking

Y = Last Digit of Year (ex: 6 for 2016)

WW = Week Code (01 to 52)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	DF 005S	DF 01S	DF 02S	DF 04S	DF 06S	DF 08S	DF 10S	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$V_{RMM} \ V_{RWM} \ V_{R}$	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	V_{RMS}	35	70	140	280	420	560	700	V
Average Forward Rectified Current @ T _A = +40°C	lo				1.0				Α
Non-Repetitive Peak Forward Surge Current, 8.3 ms Single Half Sine-Wave Superimposed on Rated Load					50				А

Thermal Characteristics

Characteristic	Symbol	DF 005S	DF 01S	DF 02S	DF 04S	DF 06S	DF 08S	DF 10S	Unit
Typical Thermal Resistance, Junction to Ambient (Note 6)	$R_{\theta JA}$	40			°C/W				
Operating and Storage Temperature Range	T _J , T _{STG}			-	65 to +15	0			°C

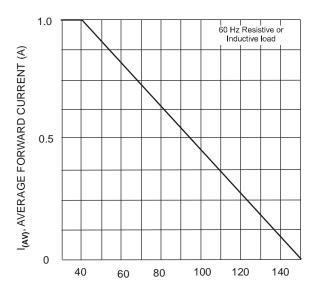
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	DF 005S	DF 01S	DF 02S	DF 04S	DF 06S	DF 08S	DF 10S	Unit
Forward Voltage (Per Element)	@ I _F = 1.0A	V_{FM}				1.1				V
Peak Reverse Current at Rated DC Blocking Voltage (Per Element)	@ T _A = +25°C @ T _A = +125°C	I _{RM}				10 500				μΑ
I ² t Rating for Fusing (t<8.3ms)		l ² t				10.4				A ² s
Typical Total Capacitance (Per Element) (Note 5)		Ст				25				pF

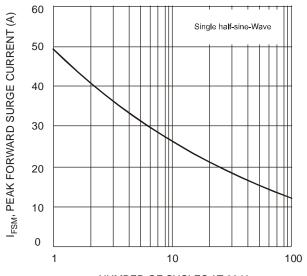
Notes:

^{5.} Measured at 1.0 MHz and applied reverse voltage of 4.0V DC.
6. Thermal resistance, junction to ambient, measured on PC board with 5.0mm² (0.03mm thick) land areas.

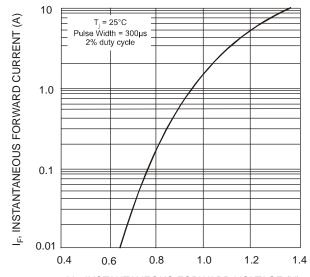




T_A, AMBIENT TEMPERATURE (°C) Fig. 1 Output Current Derating Curve



NUMBER OF CYCLES AT 60 Hz Fig. 3 Max Non-Repetitive Peak Forward Surge Current



 $V_{\rm F}$, INSTANTANEOUS FORWARD VOLTAGE (V) Fig. 2 Typical Forward Characteristics (per element)

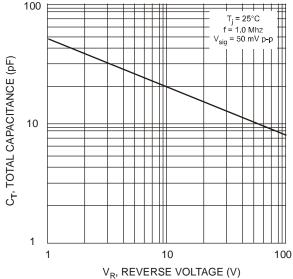
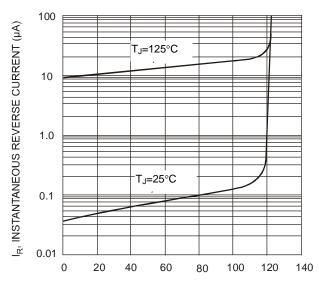


Fig. 4 Typical Total Capacitance (per element)

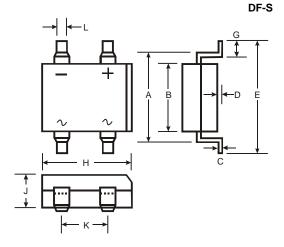




PERCENT OF RATED PEAK REVERSE VOLTAGE (%) Fig. 5 Typical Reverse Characteristics (per element)

Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

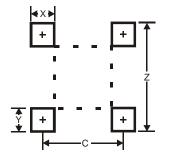


DF-S					
Dim	Min	Max			
Α	7.40	7.90			
В	6.20	6.50			
C	0.22	0.30			
D	0.076	0.33			
Е		10.40			
G	1.02	1.53			
Ŧ	8.13	8.51			
7	2.40	2.60			
K	5.00	5.20			
L	1.00	1.20			
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

DF-S



Dimensions	Value (in mm)
Z	10.26
Х	1.2
Y	1.52
С	5.2



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